

11/27/01

438	Class	Subclass	ISSUE CLASSIFICATION
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PATENT NUMBER

U.S. UTILITY Patent Application

<p>5 O.I.P.E.</p> <p>SCANNED <u>14</u> Q.A. <u>W8</u></p>	<p>PATENT DATE</p>
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APPLICATION NO. 09/993890	CONT/PRIOR F	CLASS 438	SUBCLASS 257	ART UNIT 2812	EXAMINER J. M. Lee
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APPLICANTS

Satoru Yamagata
Masanori Yoshimi

TITLE

Method for manufacturing nonvolatile semiconductor memory with narrow variations in threshold voltages of memory cells

PTO-2040
12/99

ISSUING CLASSIFICATION

ORIGINAL					CROSS REFERENCE(S)					
CLASS		SUBCLASS			CLASS	SUBCLASS (ONE SUBCLASS PER BLOCK)				
438										
INTERNATIONAL CLASSIFICATION										

☐ Continued on Issue Slip Inside File Jacket

<input type="checkbox"/> TERMINAL DISCLAIMER	DRAWINGS			CLAIMS ALLOWED	
	Sheets Drwg. <i>10</i>	Figs. Drwg. <i>27</i>	Print Fig. <i>5B, 5C, 5D</i>	Total Claims	Print Claim for O.G.
<input type="checkbox"/> The term of this patent subsequent to _____ (date) has been disclaimed.	<i>Calhoun</i> (Assistant Examiner) (Date)			NOTICE OF ALLOWANCE MAILED	
<input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S. Patent. No. _____ _____ _____				ISSUE FEE	
	Amount Due	Date Paid			
<input type="checkbox"/> The terminal ____ months of this patent have been disclaimed.	_____ (Legal Instruments Examiner) (Date)			ISSUE BATCH NUMBER	
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